



DB-55008L-880

RF POWER AMPLIFIER USING 1 x PD55008L

PRELIMINARY DATA

N-CHANNEL ENHANCEMENT-MODE LATERAL MOSFETs

GENERAL FEATURES

- EXCELLENT THERMAL STABILITY
- FREQUENCY 800 - 880 MHz
- SUPPLY VOLTAGE 12.5 V
- OUTPUT POWER 7 W
- POWER GAIN 14.1 +/- 0.7 dB
- EFFICIENCY 53% - 62%
- LOAD MISMATCH 20:1
- BeO FREE AMPLIFIER

DESCRIPTION

The DB-55008L-880 is a common source N-Channel Enhancement-Mode Lateral Field Effect RF power amplifier designed for 800 MHz mobile radios.

Figure 1. Demo Board (Picture)

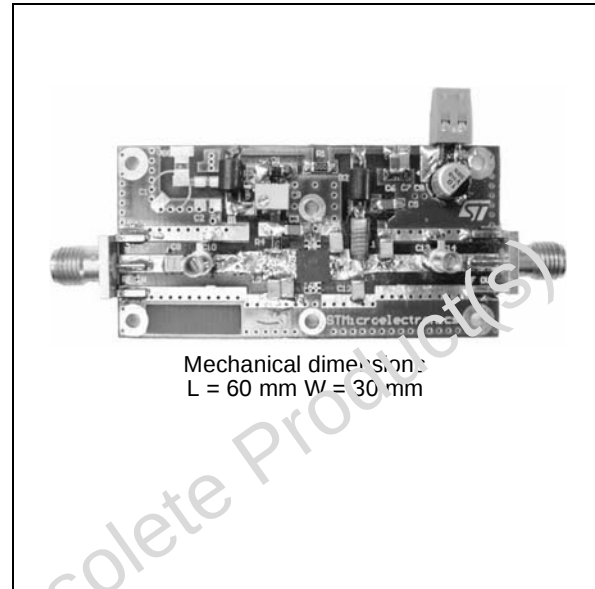


Table 1. Order Codes

Package	Order Code
PowerFLAT™ (5x5)	DB-55008L-880

Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V _{DD}	Supply voltage	16	V
I _D	Drain current	1.3	A
P _{DISS}	Power Dissipation	8	W
T _{CASE}	Operate Case Temperature	-20 to +85	°C
T _{amb}	Max. Ambient Temperature	55	°C

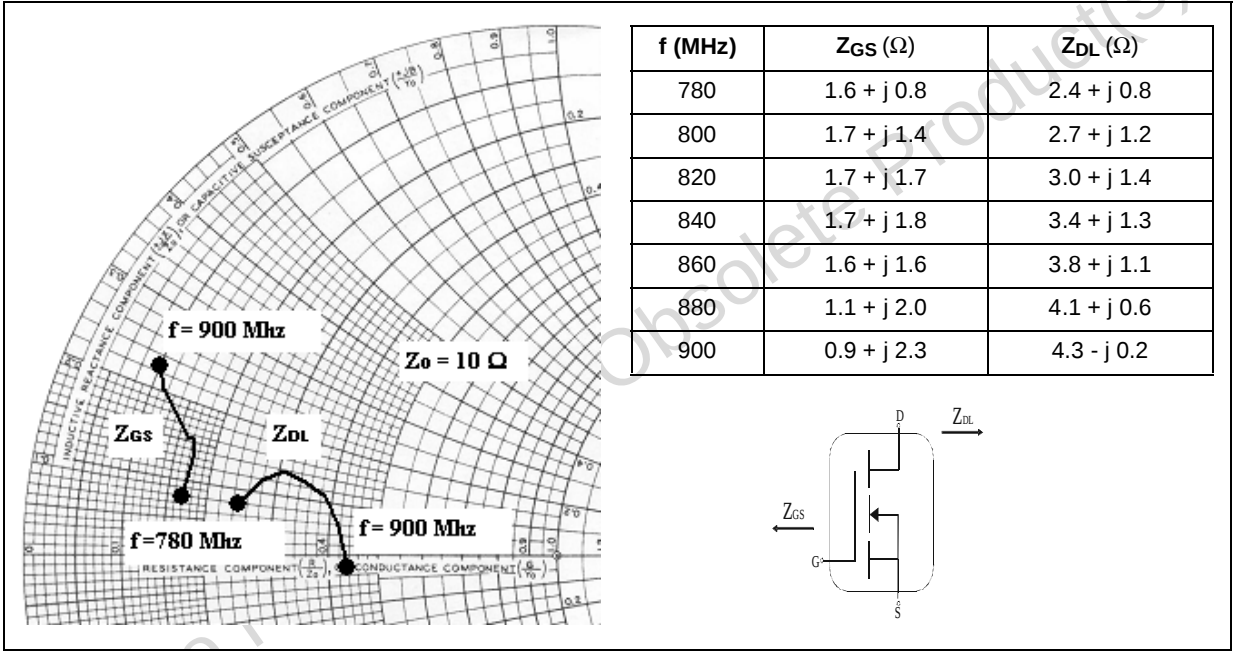
ELECTRICAL CHARACTERISTICS

($T_{amb} = +25^{\circ}\text{C}$, $V_{DD} = 12.5\text{ V}$, $I_{DQ} = 150\text{mA}$, unless otherwise specified)

Table 3. RF Data

Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Unit
f	Frequency range		800		880	MHz
P_{out}	Output Power			7		W
G_p	Power Gain	$P_{OUT} = 7\text{ W}$		14.1		dB
N_D	Efficiency	$P_{OUT} = 7\text{ W}$	53			%
	Gain Flatness	$P_{OUT} = 7\text{ W}$			+/- 0.7	dB
H2	2nd Harmonic	$P_{OUT} = 7\text{ W}$			-15	dBc
H3	3rd Harmonic	$P_{OUT} = 7\text{ W}$			-25	dBc
VSWR	Load Mismatch	$P_{OUT} = 6\text{ W}$, all phases		20:1		

Figure 2. Impedance data



TYPICAL PERFORMANCE

Figure 3. Output Power Vs Input Power

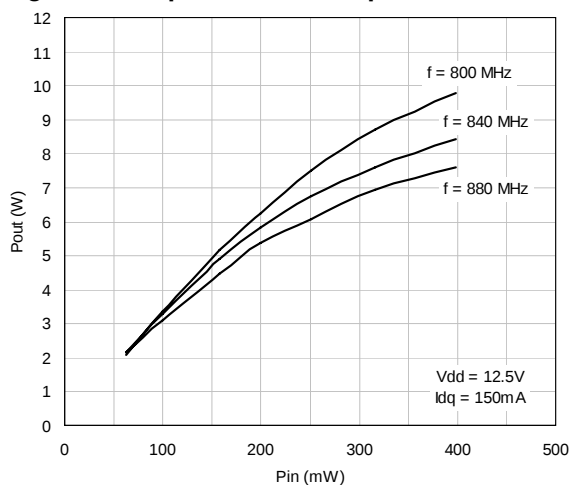


Figure 6. Efficiency Vs Output Power

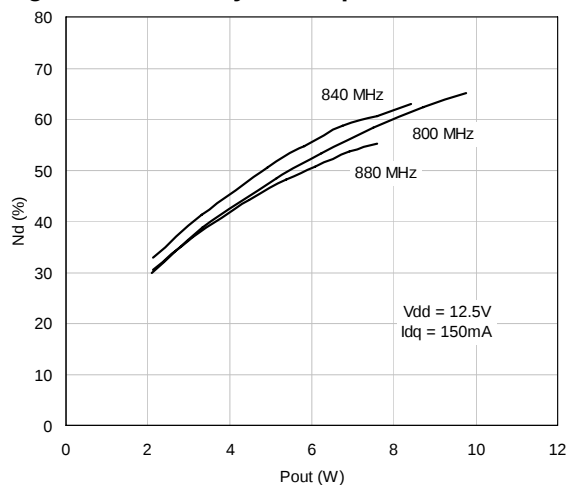


Figure 4. Gain & Efficiency Vs Frequency

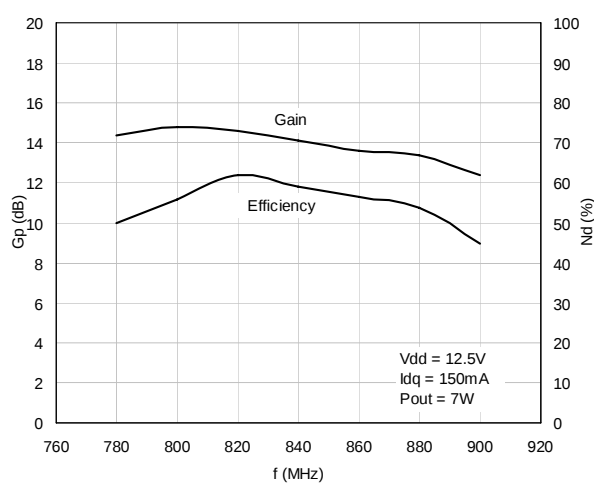


Figure 7. Input Return Loss Vs Frequency

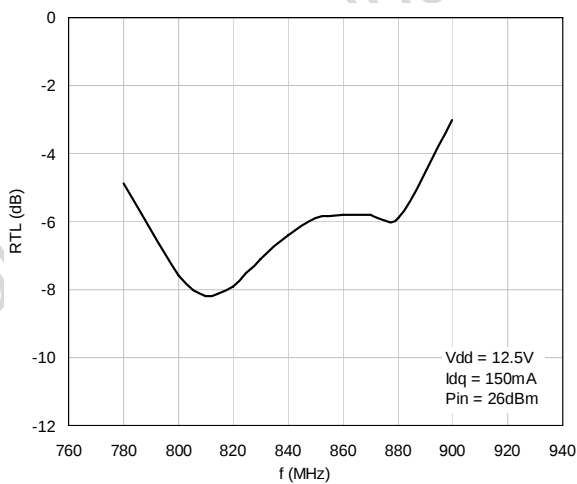


Figure 5. Output Power Vs Drain Voltage

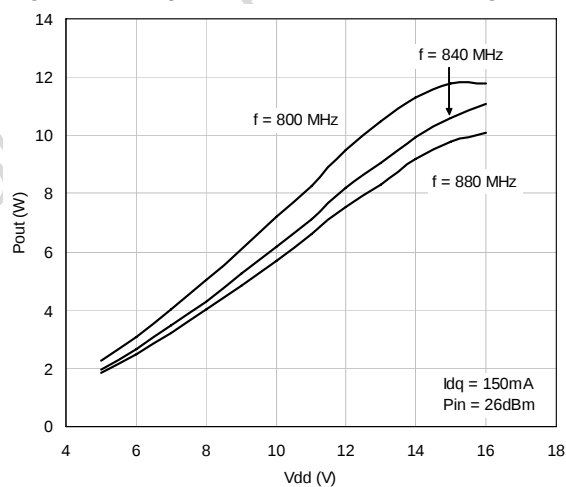


Figure 8. Test Circuit

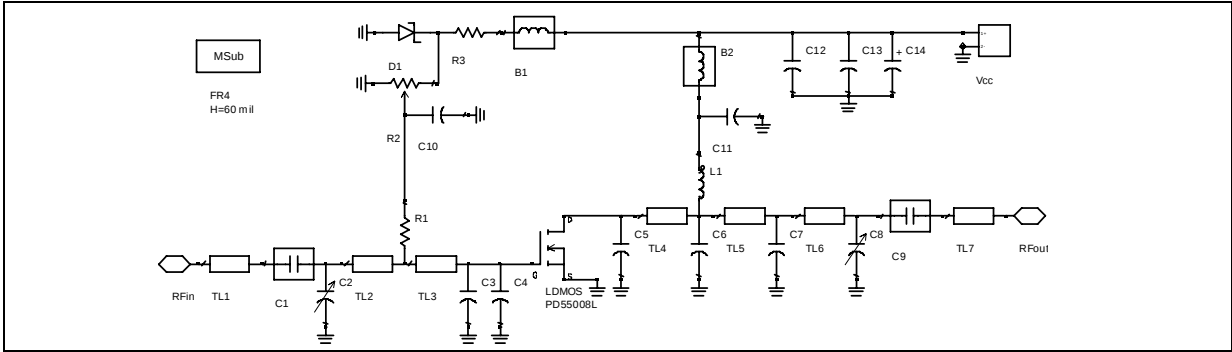


Table 4. Component Part List

Component ID	Description	Value	Case size	Manufacturer	Part Code
C1, C9	Capacitor	30 pF	100B	ATC	3R0
C2, C8	Variable Capacitor	0.8 -:- 8 pF		Johnson	27293
C3	Capacitor	4.3 pF	100B	ATC	4R3
C4, C5	Capacitor	18 pF	100B	ATC	180
C6	Capacitor	9.1 pF	100B	ATC	9R1
C7	Capacitor	8.2 pF	100B	ATC	8R2
C10	Capacitor	120 pF	1206	Murata	GRM42-6C0G121J50
C11	Capacitor	120 pF	1206	Murata	GRM42-6C0G121J50
C12	Capacitor	1 nF	1206	Murata	GRM42-6C0G102J50
C13	Capacitor	10 nF	1206	Murata	GRM42-6X7R104K50
C14	Capacitor	10 uF	SMT	Panasonic	EEVHB1V100P
L1	Inductor	35.5 nH		Coilcraft	B09T
B1	Ferrite Bead			PANASONIC	EXCELDRC35C
B2	Ferrite Bead			PANASONIC	EXCELDRC35C
R1	Resistor	15	1206	TYCO ELECTRONICS	01623429-1
R2	Potentiometer	10 K		BOURNS ELECTRONICS	3214W-1-103E
R3	Resistor	1 K	1206	TYCO ELECTRONICS	01623440-1

D1	Zener Diode	5.1 V	SOD110	PHILIPS	BZX284C5V1
TL1	Transmission Line	-	W = 2.87 mm, L = 8.6 mm		
TL2	Transmission Line	-	W = 2.87 mm, L = 12.7 mm		
TL3, TL4	Transmission Line	-	W = 4.9 mm, L = 5.8 mm		
TL5	Transmission Line	-	W = 2.87 mm, L = 2 mm		
TL6	Transmission Line	-	W = 2.87 mm, L = 10 mm		
TL7	Transmission Line	-	W = 2.87 mm, L = 7.5 mm		
RF in	SMA-CONN			Johnson	142-0701-801
RF out	SMA-CONN			Johnson	142-0701-801
PD55008L	LDMOS			STMicroelectronics	PD55008L

Figure 9. Photomaster

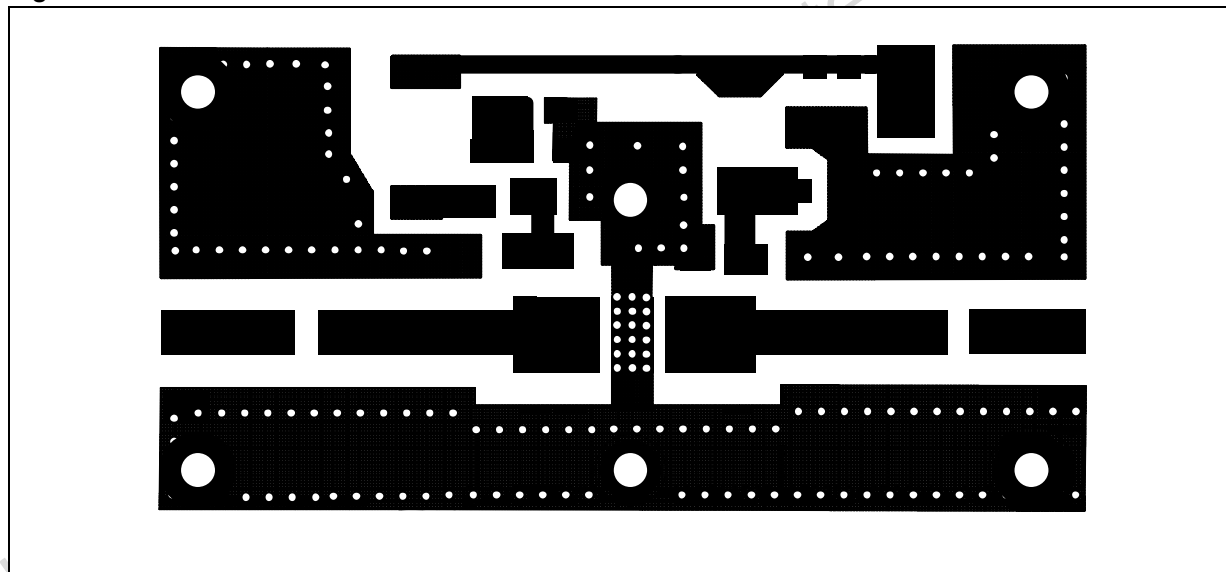
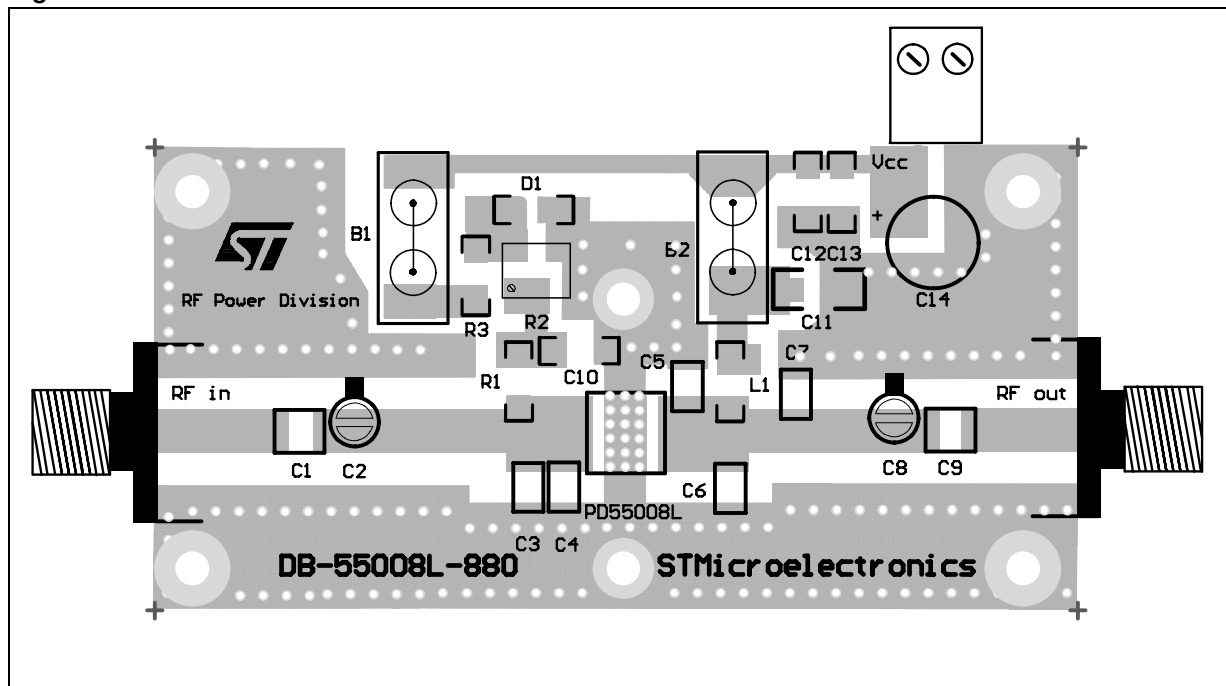


Figure 10. Circuit

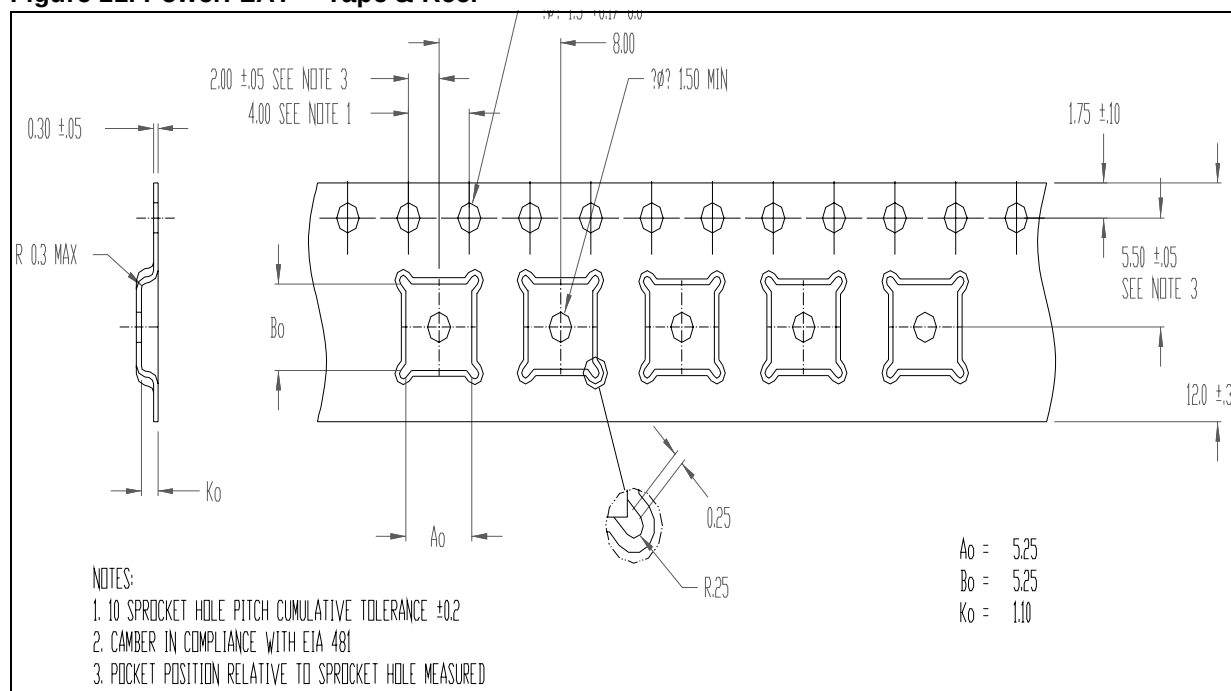


TAPE & REEL

Table 5. PowerFLAT™ Tape & Reel Dimensions

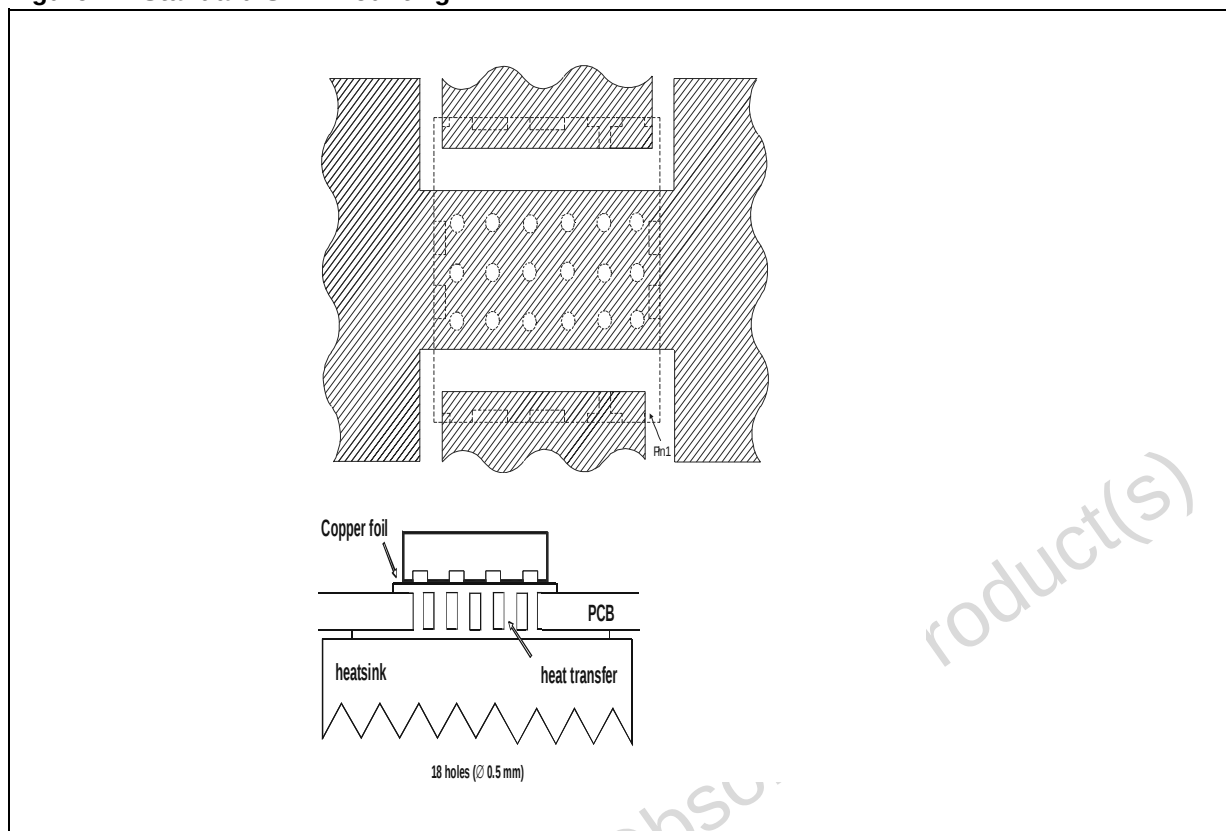
DIM.	mm.		
	MIN.	TYP	MAX.
Ao	5.15	5.25	5.35
Bo	5.15	5.25	5.35
Ko	1.0	1.1	1.2

Figure 11. PowerFLAT™ Tape & Reel



MOUNTING INDICATIONS

Figure 12. Standard SMD Mounting

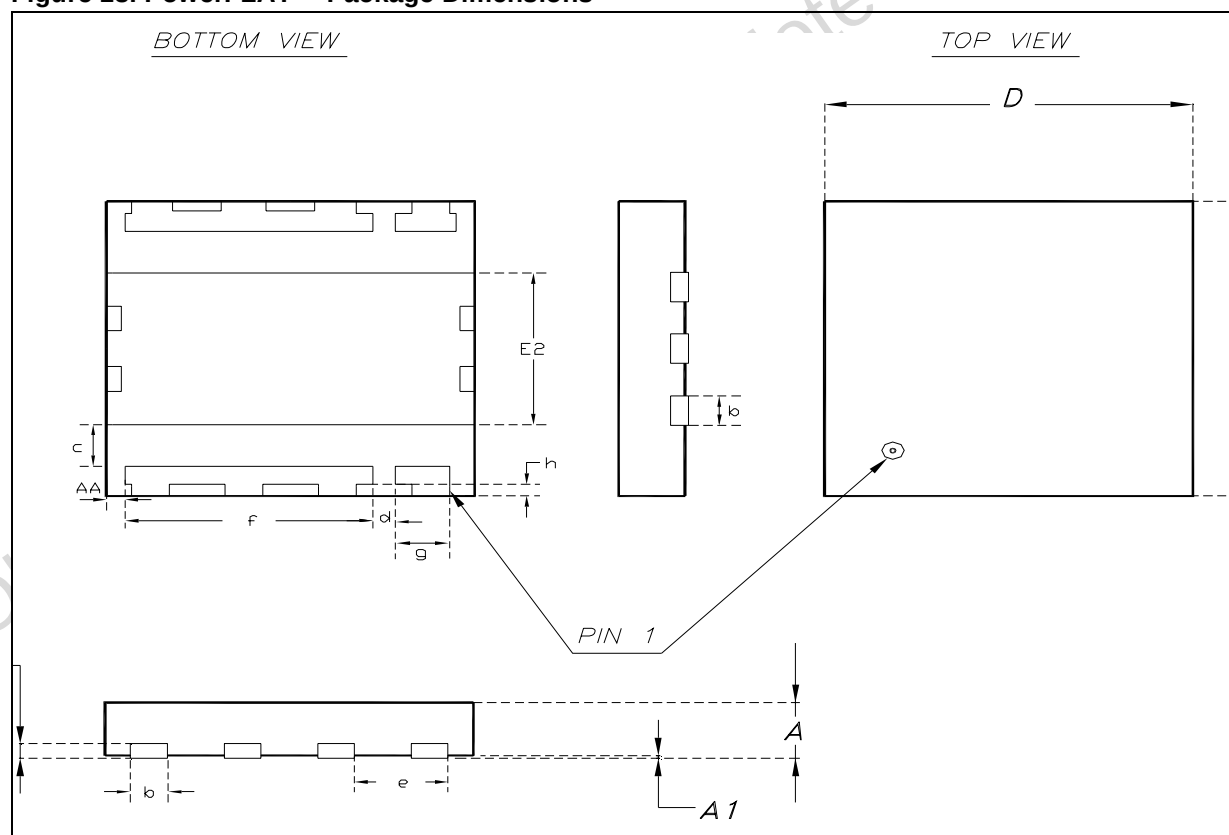


PACKAGE MECHANICAL

Table 6. PowerFLAT™ Mechanical Data

DIM.	mm			inch		
	MIN.	TYP	MAX.	MIN.	TYP	MAX.
A		0.90	1.00		0.035	0.039
A1		0.02	0.05		0.001	0.002
A3		0.24			0.009	
AA	0.15	0.25	0.35	0.006	0.01	0.014
b	0.43	0.51	0.58	0.017	0.020	0.023
c	0.64	0.71	0.79	0.025	0.028	0.031
D		5.00			0.197	
d		0.30			0.011	
E		5.00			0.197	
E2	2.49	2.57	2.64	0.098	0.101	0.104
e		1.27			0.050	
f		3.37			0.132	
g		0.74			0.03	
h		0.21			0.008	

Figure 13. PowerFLAT™ Package Dimensions



REVISION HISTORY

Table 7. Revision History

Date	Revision	Description of Changes
14-Sep-2005	1	First Issue.
12-Dec-2005	2	New component part list

Obsolete Product(s) - Obsolete Product(s)

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